

# Cryogenic STM/STS observations of Pb-doped $\text{Bi}_2\text{Sr}_2\text{CuO}_y$ single crystals

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## Abstract

Cleaved ab-surfaces of Pb-doped  $\text{Bi}_2\text{Sr}_2\text{CuO}_y$  (Bi2201) single crystals were probed by scanning tunnelling microscopy/spectroscopy (STM/STS) at cryogenic temperatures below  $T_c$ . The obtained STS spectra clearly indicate a d-wave like gap structure superimposed on inverse V-shaped background, similar to the previous STS observations on pure Bi2201. Furthermore, we found that the gap value  $\Delta$  was spatially non-uniform in a nanometer scale and ranged from 20 to 30 meV.

*Key words:* Bi2201; STM/STS; superconducting gap;

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## 1. Introduction

Scanning tunneling spectroscopy (STS) has been extensively used for the elucidation of the pseudo-gap state in a high temperature superconductor,  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_y$  (Bi2212) in various doping levels [1,2]. As a result, it has been clarified that the superconducting gap changes into the pseudo-gap almost continuously at  $T_c$ , and that the pseudo-gap state survives up to room temperature in the underdoped or optimally doped compounds. Recently, similar STS measurements have been performed on  $\text{Bi}_2\text{Sr}_2\text{CuO}_y$  (Bi2201), containing a single  $\text{CuO}_2$  layer in a unit, and confirmed the pseudo-gap above  $T_c$  [6]. However, its doping dependence has not been examined yet.

In this paper, we present the results of STM/STS measurements on Pb-doped Bi2201 in the overdoped regime. The obtained STS spectra at 4.3 K revealed a granular behavior of superconductivity that superconducting and pseudo-gap-like regions are mixed up in a nanometer scale, similar to those reported on Bi2212 [3,4].

## 2. Experiment

Pb-Bi2201 single crystals were grown by a FZ method. The single crystals exhibit a superconducting diamagnetic transition at  $T_c = 10$  K. By means of inductively coupled plasma spectrometry (ICP), their chemical composition was determined as  $\text{Bi}_{1.83}\text{Pb}_{0.37}\text{Sr}_{1.91}\text{CuO}_y$ . The base pressure of the STM chamber was maintained at less than  $2 \times 10^{-11}$  Torr during the measurements. The single crystals were cleaved at 77 K to avoid oxygen loss from the surfaces. STM tips used in this study were mechanically sharpened Pt/Ir wires.

## 3. Results and discussion

Fig. 1 is an STM image taken on the cleaved ab plane of a Pb-Bi2201 single crystal at 4.3 K. The figure clearly indicates a two-dimensional atomic arrangement separated by 0.35 nm, which is comparable with the a- or b-axis length of Pb-Bi2201 unit cell [5]. In the present Pb-Bi2201 samples, we did not observe any sign of phase separation into Pb-rich and Pb-poor re-

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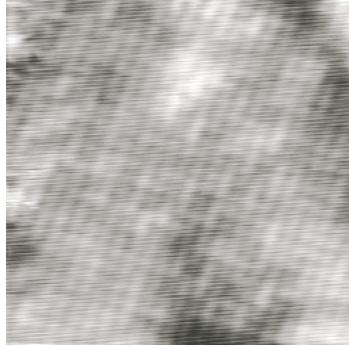


Fig. 1. Constant current STM image on the cleaved ab surface of Pb-Bi2201 single crystal at 4.3 K. The scanning area is  $7.5 \times 7.5 \text{ nm}^2$ . The sample bias voltage and set-point current are  $V_s = 100 \text{ mV}$  and  $I_t = 0.4 \text{ nA}$ , respectively.

gions, as seen in heavily Pb doped Bi2212. From Fig. 1, it is notable that in the present Pb-Bi2201 the modulation along the b-axis completely disappears. This is in sharp contrast to Pb-Bi2212, in which the modulation survives, at least, up to  $x \sim 0.4$ , although the modulation period is expanded along with  $x$ .

Fig. 2(a) is a spatial map of the gap value  $\Delta$ , defined as the energy separation between conductance peaks. As can be seen,  $\Delta$  is non-uniform and is substantially distributed, ranging from 20 to 30 meV, over the scanned area of  $9 \times 9 \text{ nm}^2$ .

$\Delta$  varies on a scale of 1-2 nm, which is in accordance with the in-plane coherence length. These features are essentially same as those observed in Bi2212 in the underdoped and optimally doped regimes. Therefore, it can be concluded that the inhomogeneity in  $\Delta$  is an inherent nature of Bi-based cuprates in common, irrespective of carrier number. However, relative standard deviation of  $\Delta$ ,  $\delta\Delta/\Delta$ , as a measure of the magnitude of inhomogeneity, is fairly smaller than those of pure Bi2212 and Pb-doped Bi2212 [3,4]. This suggests that the random potential introduced by Pb atoms is not a major cause of the gap inhomogeneity observed here.

The site-specified tunneling spectra observed on the locations A and B in Fig. 2 (a) are shown in Fig. 2(b), as previously reported in pure Bi2201 [6]. Both spectra exhibit an inverse-V shaped background, which may be due to the van Hove singularity. Notably, the zero bias conductance of curve B is much lower than that of A, while the coherence peak at B is substantially depressed. The similar tendencies have also been found in underdoped and optimally doped Bi2212 [3,4]. Opening of a relatively wide gap accompanied with the suppression of conductance peaks has been frequently argued as a typical character of pseudo-gap state, so that the present STS results suggest nano-scale phase separation into superconducting and pseudo-gap domains.

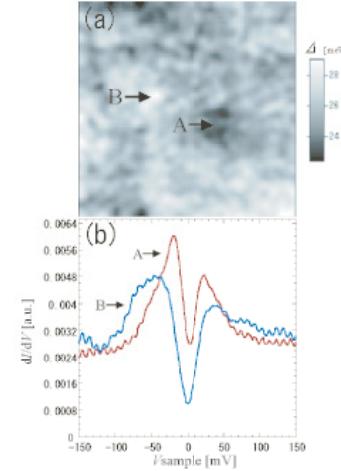


Fig. 2. (a)  $\Delta$  distribution on the cleaved ab surface of Pb-Bi2201 at 4.3 K. The scanning area is  $7.5 \times 7.5 \text{ nm}^2$ . (b) Tunneling spectra at the locations A and B in Fig. 2(a).

#### 4. Summary

We have performed low temperature STM/STS measurements on Pb-doped Bi2201 at 4.3 K. The gap value  $\Delta$  evaluated from the STS spectra was found to be spatially non-uniform, as seen in Bi2212, although the extent of gap inhomogeneity is relatively smaller. The coherent peaks tend to be suppressed, and, at the same time, zero bias conductance is lowered, as  $\Delta$  is increased. These findings lead to a conclusion that granular superconductivity is a general feature of Bi-based cuprates, regardless of number of CuO planes and carrier concentration.

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